



Attorney Docket No. 1789.1040CIP

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Shinya MYOJIN, et al.

Application No.: 10/644,220

ATTENTION

Confirmation No.: 6469

CERTIFICATE OF CORRECTION

Filed: August 21, 2003

BRANCH

U.S. Patent No.: 7,291,231

Issued: November 6, 2007

For: COPPER-NICKEL-SILICON TWO PHASE QUENCH SUBSTRATE

REQUEST FOR CERTIFICATE OF CORRECTION

Commissioner for Patents
PO Box 1450
Alexandria, VA 22313-1450

Certificate
JAN 25 2008
of Correction

Sir:

Patentees respectfully request that a Certificate of Correction be issued in the subject patent, pursuant to 35 USC § 254 and 37 CFR § 1.322, to correct the errors shown on the attached Form PTO-1050. A check in the amount of \$100 to cover the cost of the Certificate is attached.

One or more of the errors shown on the attached Form PTO-1050 are within the responsibility of the undersigned; each thereof is of a clerical or typographical nature or of minor character and occurred in good faith, and the correction thereof is consistent with the prosecution record.

Respectfully submitted,

STAAS & HALSEY LLP

Date: January 18, 2008

By: David M. Pitcher
David M. Pitcher
Registration No. 25,908
01 FEB 2008

1201 New York Ave, N.W., 7th Floor
Washington, D.C. 20005
Telephone: (202) 434-1500
Facsimile: (202) 434-1501

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CERTIFICATE OF CORRECTION

PATENT NO : 7,291,231

DATED : November 6, 2007

INVENTOR(S) : Shinya MYOJIN, et al.

It is certified that error appears in the above-identified patent and that said Letters Patent are hereby corrected as shown below:

First Page, Column 1 (Inventors), Line 3, change "Nicholes" to --Nicholas--.

First Page, Column 1 (U.S. Patent Documents), Line 2, change
"4,290,435 A 9/1981 Waggott" to
--4,260,435 A 4/1981 Edens et al.--.

Column 11, Line 31-32, change "copper-nickel silicon" to
--copper-nickel-silicon--.

Column 11, Line 37, change "copper-nickel silicon" to
--copper-nickel-silicon--.

MAILING ADDRESS OF SENDER:
STAAS & HALSEY LLP
1201 New York Avenue, N.W.
7th Floor
Washington, DC 20005

PATENT NO. 7,291,231

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